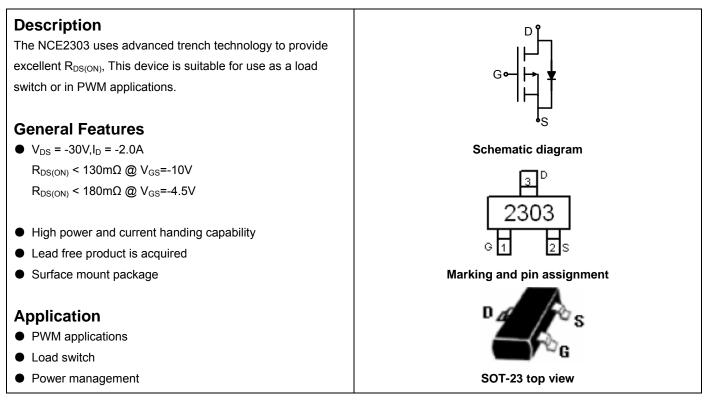




NCE P-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

	0	0			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2303	NCE2303	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	ID	-2.0	A
Drain Current-Pulsed (Note 1)	I _{DM}	-10	A
Maximum Power Dissipation	PD	1.0	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{θJA}	125	°C/W
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Electrical Characteristics (T_A=25[°]Cunless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-30	-33	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-30V, V_{GS} =0V	-	-	-1	μA



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1	-1.6	-2.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-10V, I _D =-2.0A	-	72	130	mΩ
Drain-Source On-State Resistance		V _{GS} =-4.5V, I _D =-1.5A	-	110	180	mΩ
Forward Transconductance	g fs	V _{DS} =-10V,I _D =-2A		2	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C _{lss}		-	226	-	PF
Output Capacitance	C _{oss}	F=1.0MHz	-	47	-	PF
Reverse Transfer Capacitance	Crss		-	28	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	9	-	nS
Turn-on Rise Time	tr	V_{DD} =-15V,RL=15 Ω	-	9	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =-10V,R _{GEN} =6Ω	-	18	-	nS
Turn-Off Fall Time	t _f		-	6	-	nS
Total Gate Charge	Qg		-	8.5	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =-15V,I _D =-2.0A,V _{GS} =-10V	-	2.3	-	nC
Gate-Drain Charge	Q _{gd}	1	-	1.5	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-2.0A	-	-	-1.2	V

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production





NCE2303

Typical Electrical and Thermal Characteristics

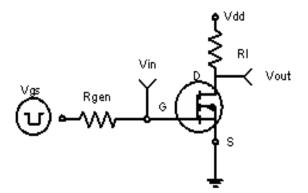
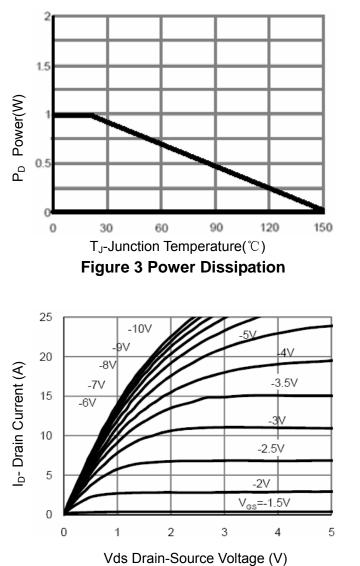
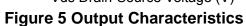


Figure 1:Switching Test Circuit





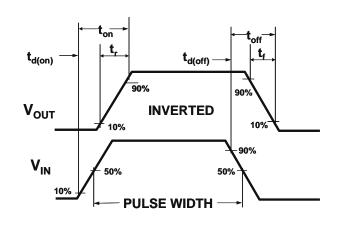
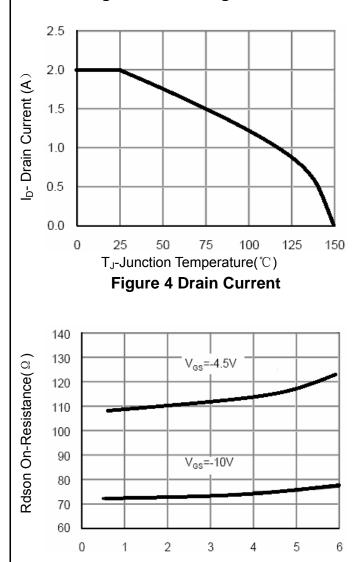


Figure 2:Switching Waveforms



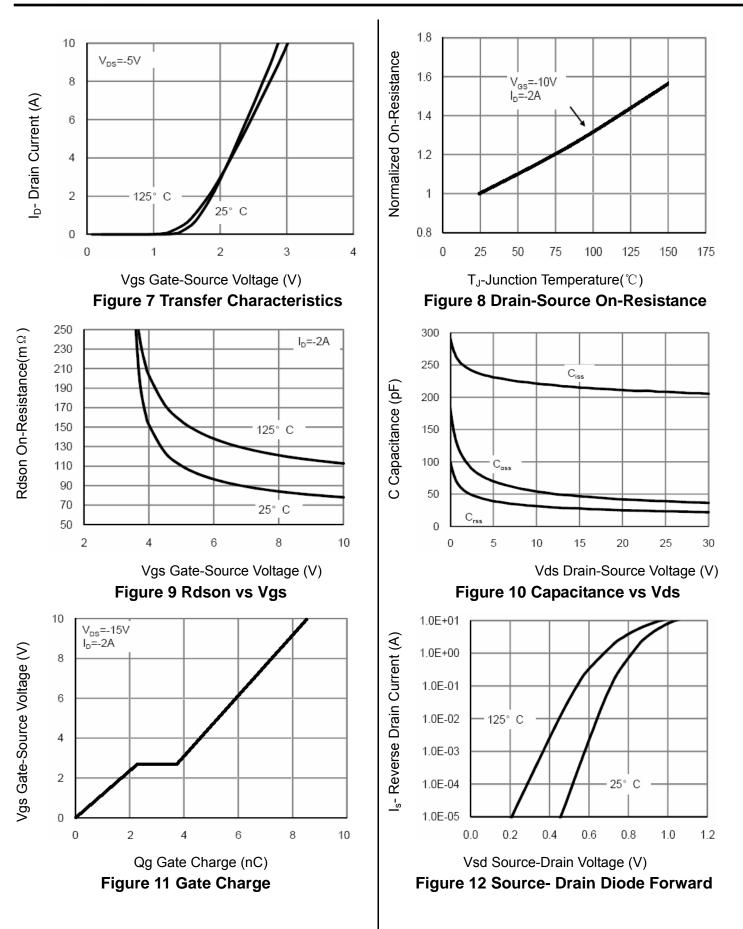
I_D- Drain Current (A) Figure 6 Drain-Source On-Resistance



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Pb Free Product

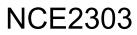
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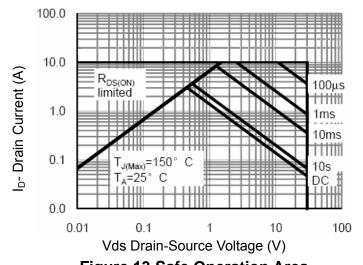


Figure 13 Safe Operation Area

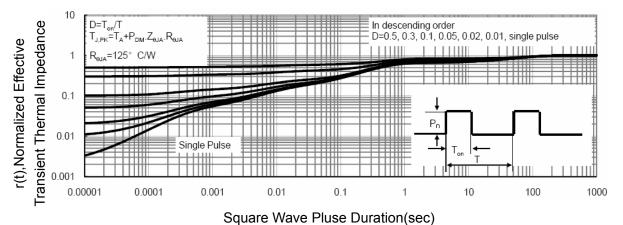
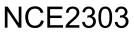
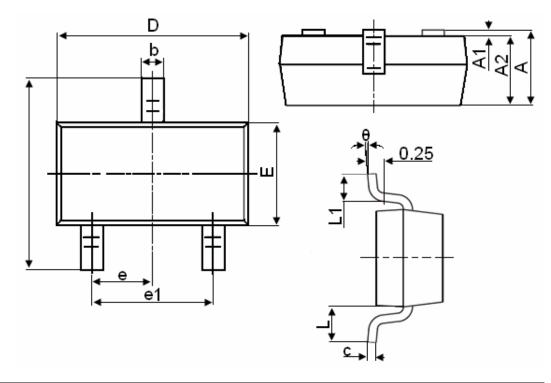


Figure 14 Normalized Maximum Transient Thermal Impedance





SOT-23 Package Information



Symbol	Dimensions in Millimeters				
Symbol	MIN.	MAX.			
A	0.900	1.150			
A1	0.000	0.100			
A2	0.900	1.050			
b	0.300	0.500			
с	0.080	0.150			
D	2.800	3.000			
E	1.200	1.400			
E1	2.250	2.550			
е		0.950TYP			
e1	1.800	2.000			
L	0.550REF				
L1	0.300	0.500			
θ	0°	8°			

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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